

Bluetooth® 4.2 Stereo Audio SoC

Features

- · Qualified for Bluetooth v4.2 specifications
- Supports HFP 1.6, HSP 1.2, A2DP 1.3, SPP 1.2 and AVRCP 1.6
- Supports Bluetooth 4.2 dual-mode (BDR/EDR/ BLE) specifications (FW dependent):
 - Generic access service
 - Device information service
 - Proprietary services for data communication
 - Apple Notification Center Service (ANCS)
- Supports high resolution, up to 24-bit, 96 kHz audio data format
- I²S digital audio, microphone, analog audio and AUX-In
- · Supports one microphone input
- · UART, GPIOs and LEDs
- · Supports firmware field upgrade
- · Battery charging

Baseband Features

- · 16 MHz main clock input
- · Built-in Flash memory for programing (8 Mbit)
- Connects simultaneously two hosts (smartphone and tablet) with HFP/A2DP profiles
- Adaptive Frequency Hopping (AFH)

Audio Codec

- Sub-band coding (SBC) and optional Advanced Audio Coding (AAC) decoding
- 20-bit digital-to-analog converter (DAC) with 98 dB SNR
- 16-bit analog-to-digital converter (ADC) with 92 dB SNR
- Supports up to 24-bit, 96 kHz I²S digital audio

RF Features

- Class 2 output power (+2 dBm typical)
- Receive sensitivity: -90 dBm (2 Mbps EDR)
- Combined Tx/Rx RF terminal simplifies external matching and reduces external antenna switches
- Tx/Rx RF switch for Class 2 or Class 3 applications
- Integrated synthesizer requires no external voltage-controlled oscillator (VCO), varactor diode, resonator and loop filter
- Crystal oscillator with built-in digital trimming compensates for temperature or process variations

DSP Audio Processing

- · 32-bit DSP core
- Supports 64 kbps A-Law, μ-Law PCM format/Continuous Variable Slope Delta (CVSD) Modulation for Synchronous Connection-Oriented (SCO) channel operation
- Supports 8/16 kHz noise suppression
- Supports 8/16 kHz echo cancellation
- Supports Modified Sub-Band Coding (MSBC) decoder for wideband speech (WBS)
- Built-in High Definition Clean Audio (HCA) algorithms for both narrow band and wide band speech processing
- Packet loss concealment (PLC)
- Built-in audio effect algorithms to enhance audio streaming
- Supports Serial Copy Management System (SCMS-T) content protection

Packages

Туре	LGA
Pin count	68
Contact/Lead pitch	0.4
Dimensions	8x8x0.9 mm

Peripherals

- High-speed HCI-UART interface (supports up to 921,600 bps)
- Built-in lithium-ion and lithium-polymer battery charger (up to 350 mA)
- Integrated 1.8V and 3V configurable switching regulator and low-dropout (LDO) regulator
- Built-in ADC for battery monitoring and voltage sensor
- · An AUX-In port for external audio input
- · Three LED drivers

Operating Condition

Operating voltage: 3.2V to 4.2V
Temperature range: -20°C to +70°C

Applications

- · Soundbars and Subwoofers
- · Speakerphones
- · Headsets and headphones

Description

The IS2063 is a stereo audio SoC qualified for Bluetooth v4.2 with Enhanced Data Rate (EDR). It integrates a 32-bit DSP co-processor and a codec which is dedicated for voice and audio applications. For voice applications, the CVSD encoding/decoding, 8K/16K noise reduction and echo cancellation are implemented. For audio applications, the SBC and AAC Low-Complexity (AAC-LC) decoding functions

The IS2063 SoC features a 20-bit audio DAC in addition to an I^2S digital audio interface that supports up to 24-bit, 96 kHz data formats. The system optimization includes an integrated battery voltage sensor, a battery charger, a switching regulator and LDOs.

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NOTES:

1.0 **DEVICE OVERVIEW**

The IS2063 SoC integrates a Bluetooth 4.2 dual-mode radio transceiver, a Power Management Unit (PMU), a Microcontroller (MCU), an audio codec, a crystal oscillator, a 32-bit DSP and a Flash, as illustrated in Figure 1-1. The IS2063 SoC can be configured using the UI tool.

Note: The UI tool is a Windows-based configuration utility tool, which is available for download from the Microchip web site at: www.microchip.com/IS2063.

Figure 1-1 illustrates a typical block diagram of the IS2063 SoC.

FIGURE 1-1: **IS2063 SOC BLOCK DIAGRAM**

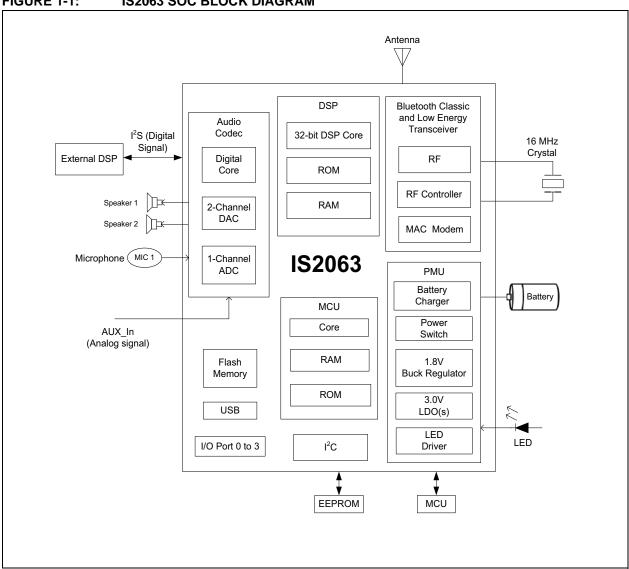


Table 1-1 provides the key features of the IS2063 SoC.

TABLE 1-1: IS2063 KEY FEATURES

Feature	IS2063		
Application	Multi-speaker/Soundbar/Subwoofer		
Stereo/mono	Stereo		
Pin count	68		
Dimensions (mm ²)	8 x 8		
Audio DAC output	2 channel		
DAC (single-ended) SNR at 2.8V (dB)	-98		
DAC (capless) SNR at 2.8V (dB)	-96		
ADC SNR at 2.8V (dB)	-92		
I ² S digital interface	Yes		
Analog AUX-In	Yes		
Mono microphone	1		
External audio amplifier interface	Yes		
UART	Yes		
USB	Yes		
LED driver	3		
Internal DC-DC step down regulator	Yes		
DC 5V adapter input	Yes		
Battery charger (350 mA max.)	Yes		
ADC for thermal charger protection	No		
Undervoltage protection (UVP)	No		
GPIO	15		
Button support	6		
NFC (triggered by external NFC)	Yes		
EEPROM	128K		
Voice prompt (FW dependent)	8K sampling rate. Stored in EEPROM with approximately 800 bytes/second		
Multitone	Yes		
DSP sound effect	Yes		
BLE Yes			
Bluetooth profiles			
HFP	1.6		
AVRCP	1.6		
A2DP	1.3		
HSP	1.2		
SPP	1.2		

Figure 1-2 illustrates the pin diagram of the IS2063 SoC.

FIGURE 1-2: **IS2063 SOC PIN DIAGRAM** VCC_RF AOHPR P0_5 P3_0 68 67 66 65 64 63 62 61 60 59 58 57 56 55 54 53 52 VDDAO 1 51 XO_P XO_N **AOHPM** 2 50 ULPC_VSUS AOHPL 3 49 VBG VDDA 48 4 VCOM 5 47 RFLDO_O MIC_N1 6 75 80 46 PMIC_IN 7 CLDO_O MIC_P1 45 DP MIC_BIAS 8 44 71 76 81 43 DM 9 AIR AVDD_USB 42 10 AIL 41 EAN VDD_CORE 11 P1_2 12 P0_3 P1_3 73 78 83 39 P0_0 13 RST_N 14 P3_5 **EXPOSED GROUND PAD** VDD_IO 15 37 P3_7 36 LED 1 P0_1 P2_4 35 LED 2 17 22 23 24 25 26 27 P1_5 BK O P0_4 HCI_RXD ADAP_IN ADC_IN SAR_VDD SYS_PWR LED 3 HCI_TXD BK_VDD CODEC_VO LDO31_VIN LD031_V0

Table 1-2 provides the pin description of the IS2063 SoC. Users can configure these pins using the UI tool.

TABLE 1-2: IS2063 SOC PIN DESCRIPTION

Din No	Bin Type		Description
Pin No	Pin Type	Name	Description
1	Р	VDDAO	Power supply (3.3V) dedicated to codec output amplifiers; connect to the CODEC_VO pin
2	0	AOHPM	Headphone common mode output/sense input
3	0	AOHPL	Left channel analog headphone output
4	Р	VDDA	Power supply (3.3V) or reference voltage for external codec; connect to CODEC_VO pin
5	Р	VCOM	Internal biasing voltage for codec; connect a 4.7 µF capacitor to ground
6	I	MIC_N1	MIC1 mono differential analog negative input
7	ı	MIC_P1	MIC1 mono differential analog positive input
8	Р	MIC_BIAS	Electric microphone biasing voltage
9	1	AIR	Right channel, single-ended analog input
10	1	AIL	Left channel, single-ended analog input
11	Р	VDD_CORE	Core 1.2V power input; connect to CLDO_O pin; connect to GND through a 1 µF (X5R/X7R) capacitor
12	0	P1_2	I ² C SCL (EEPROM clock)
13	I/O	P1_3	I ² C SDA (EEPROM data SDA), requires external pull up resistor
14	1	RST_N	System Reset (active-low)
15	Р	VDD_IO	I/O power supply input (3.3V); connect to LDO31_VO (pin # 24); connect to GND through a 1 µF (X5R/X7R) capacitor
16	I/O	P0_1	Configurable control or indication pin (Internally pulled up if configured as an input) • FWD key when Class 2 RF (default), active-low • Class1 Tx control signal for external RF Tx/Rx switch, active-high
17	I	P2_4	System configuration pin along with P2_0 and EAN pins can be used to set the IS2063 SoC in any one of these modes: • Application mode (for normal operation) • Test mode (to change EEPROM values) • Write Flash mode (to load a new firmware into the SoC), see Table 6-1
18	I/O	P0_4	Configurable control or indication pin (Internally pulled up if configured as an input) • NFC detection pin, active-low • Out_Ind_1
19	I/O	P1_5	Configurable control or indication pin (Internally pulled up if configured as an input) NFC detection pin, active-low Slide switch detector, active-high Out_Ind_1 Multi-SPK Master/Slave mode control (FW dependent)
20	I	HCI_RXD	HCI UART data input

TABLE 1-2: IS2063 SOC PIN DESCRIPTION (CONTINUED)

Pin No	Pin Type	Name	Description		
21	0	HCI_TXD	HCI UART data output		
22	Р	CODEC_VO	LDO output for codec power		
23	Р	LDO31_VIN	LDO input, connect to SYS_PWR (pin # 29)		
24	Р	LDO31_VO	3V LDO output for VDD_IO power, do not calibrate		
25	Р	ADAP_IN	5V power adapter input		
26	Р	BAT_IN	Battery input. Voltage range: 3.2V to 4.2V, When an external power supply is connected to the ADAP_IN pin, the BAT_IN pin can be left open if battery is not connected		
27	I	ADC_IN	Analog input		
28	Р	SAR_VDD	SAR 1.8V input; connect to BK_O pin		
29	Р	SYS_PWR	System power output derived from BAT_IN or ADAP_IN		
30	Р	BK_VDD	1.8V buck VDD power input; connect to SYS_PWR pin		
31	Р	BK_LX	1.8V buck regulator feedback path		
32	Р	BK_O	1.8V buck regulator output		
33	I	MFB	 Multi-Function Button and power-on key UART RX_IND, active-high (used by host MCU to wakeup the Bluetooth system) 		
34	1	LED3	LED driver 3		
35	I	LED2	LED driver 2		
36	I	LED1	LED driver 1		
37	I/O	P3_7	Configurable control or indication pin (Internally pulled up if configured as an input) • UART TX_IND, active-low (used by Bluetooth system to wakeup the host MCU)		
38	I/O	P3_5	Configurable control or indication pin (Internally pulled up, if configured as an input)		
39	I/O	P0_0	Configurable control or indication pin (Internally pulled up if configured as an input) • Slide switch detector, active-high		
40	I/O	P0_3	Configurable control or indication pin (Internally pulled up if configured as an input) REV key (default), active-low Buzzer signal output Out_Ind_2 Class 1 Rx Control signal of external RF Tx/Rx switch, active-high		
41	I	EAN AVOD HER	External address-bus negative System configuration pin along with P2_0 and P2_4 pins, used to set the IS2063 SoC in any one of the following modes: • Application mode (for normal operation) • Test mode (to change EEPROM values) • Write Flash mode (to load a new firmware into the SoC), see Table 6-1		
42	Р	AVDD_USB	USB power input; connect to LDO31_VO pin		

TABLE 1-2: IS2063 SOC PIN DESCRIPTION (CONTINUED)

	Pin No Pin Type Name Description Description			
			-	
43	1/0	DM	Differential data-minus USB	
44	1/0	DP	Differential data-plus USB	
45	Р	CLDO_O	1.2V core LDO output, for internal use only. Connect to GND through a 1 µF capacitor	
46	Р	PMIC_IN	1.8V power input for internal blocks; connect to BK_O (pin # 32)	
47	Р	RFLDO_O	1.28V RF LDO output, for internal use only. Connect to GND through a 1 µF capacitor	
48	Р	VBG	Bandgap output reference for decoupling interference. Connect to GND through a 1 µF capacitor	
49	Р	ULPC_VSUS	ULPC 1.2V output power, maximum loading 1 mA. Connect to GND through a 1 µF capacitor	
50	I	XO_N	16 MHz crystal input negative	
51	I	XO_P	16 MHz crystal input positive	
52	Р	VCC_RF	RF power input (1.28V) for both synthesizer and Tx/Rx block, connect to RFLDO_O	
53	I/O	RTX	RF path (transmit/receive)	
54	I/O	P3_1	Configurable control or indication pin (Internally pulled up if configured as an input) • REV key (default), active-low	
55	I/O	P3_3	Configurable control or indication pin	
33	1/0	1 3_3	(Internally pulled up if configured as an input)	
			FWD key (default), active-low	
56	I/O	P3_6	Configurable control or indication pin (Internally pulled up if configured as an input) • Multi-SPK Master/Slave mode control (FW dependent)	
57	I/O	P0_2	Configurable control or indication pin (Internally pulled up if configured as an input) Play/Pause key (default)	
58	I/O	P2_0	System configuration pin along with the EAN and P2_pins, used to set the IS2063 SoC in any one of the following modes:	
			Application mode (for normal operation)	
			Test mode (to change EEPROM values)	
			 Write Flash mode (to load a new firmware into the SoC), see Table 6-1 	
			Pulse/PWM signal output	
59	I/O	P2_7	Configurable control or indication pin (Internally pulled up, if configured as an input) Volume-up key (default), active-low	
60	I/O	P3_0	Configurable control or indication pin (Internally pulled up if configured as an input) AUX-In detector, active-low	
61	I/O	TFS0	I ² S interface: left/right clock	
62	I/O	P0_5	Configurable control or indication pin (Internally pulled up if configured as an input) Volume-down key (default), active-low	

TABLE 1-2: IS2063 SOC PIN DESCRIPTION (CONTINUED)

Pin No	Pin Type	Name	Description		
63	Р	VDD_IO	I/O power supply input (3.3V); connect to LDO31_VO		
			pin		
64	I/O	DR0	I ² S interface: digital left/right data		
65	I/O	RFS0	I ² S interface: left/right clock		
66	I/O	SCLK0	I ² S interface: bit clock		
67	I/O	DT0	I ² S interface: digital left/right data		
68	0	AOHPR	Right channel analog headphone output		
69-83	Р	EP	Exposed pads, Used as ground (GND) pins		
Legend:	I= Input pin	O= Output pin	I/O= Input/Output pin P= Power pin		

Note: All I/O pins can be configured using the UI tool.



NOTES:

2.0 AUDIO

The input and output audios have different stages and each stage can be programmed to vary the gain response characteristics. For microphones, both single-ended inputs and differential inputs are supported. To maintain a high quality signal, a stable bias voltage source to the condenser microphone's FET is provided. The DC blocking capacitors can be used at both positive and negative sides of the input. Internally, this analog signal is converted to 16-bit, 8/16 kHz linear PCM data.

2.1 Digital Signal Processor

A Digital Signal Processor (DSP) is used to perform speech and audio processing. The advanced speech features, such as acoustic echo cancellation and noise reduction are inbuilt. To reduce nonlinear distortion and to help echo cancellation, an outgoing signal level to the speaker is monitored and adjusted to avoid satura-

tion of speaker output or microphone input. Adaptive filtering is also applied to track the echo path impulse in response to provide echo free and full-duplex user experience.

The embedded noise reduction algorithm helps to extract clean speech signals from the noisy inputs captured by the microphones and improves mutual understanding in communication. The advanced audio features, such as multi-band dynamic range control, parametric multi-band equalizer, audio widening and virtual bass are inbuilt. The audio effect algorithms improve the user's audio listening experience in terms of better quality audio after processing the audio signals

Figure 2-1 and Figure 2-2 illustrate the processing flow of speakerphone applications for speech and audio signal processing.

FIGURE 2-1: SPEECH PROCESSING

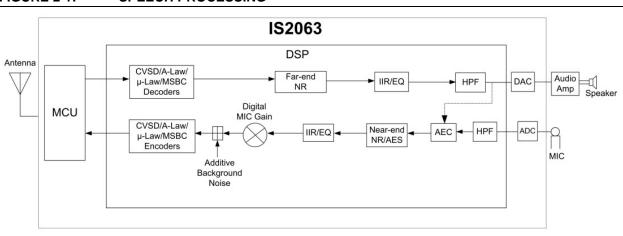
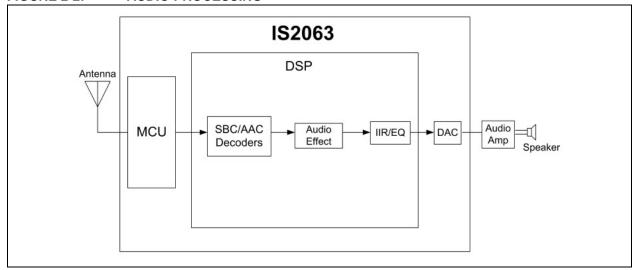


FIGURE 2-2: AUDIO PROCESSING



The DSP parameters can be configured using the DSP tool. For additional information on the DSP tool, refer to "IS206X DSP Application Note".

Note:

The DSP tool and "IS206X DSP Application Note" are available for download from the Microchip web site at: www.microchip.com/IS2063.

2.2 Codec

The built-in codec has a high signal-to-noise ratio (SNR) performance and it consists of an ADC, a DAC and an additional analog circuitry.

Figure 2-3 through Figure 2-6 illustrate the dynamic range and frequency response of the codec.



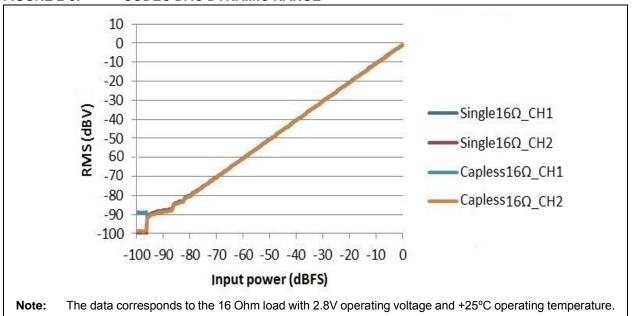
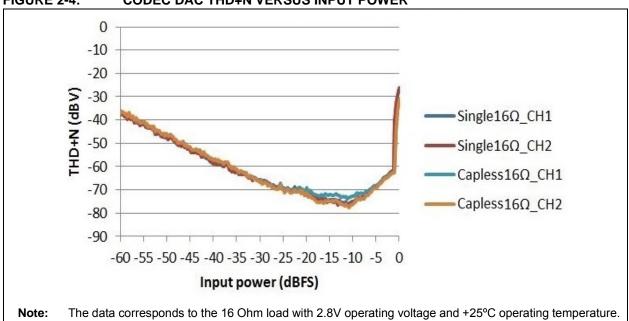


FIGURE 2-4: CODEC DAC THD+N VERSUS INPUT POWER



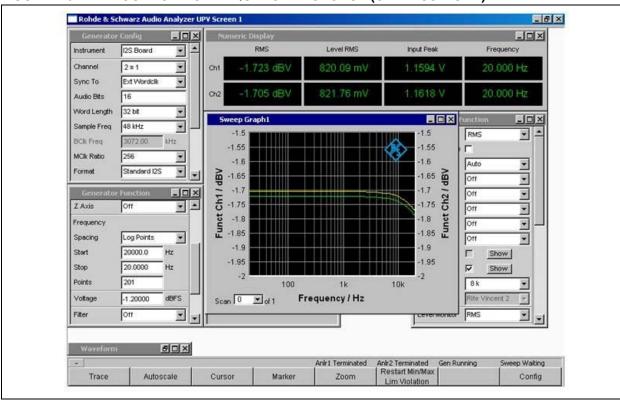
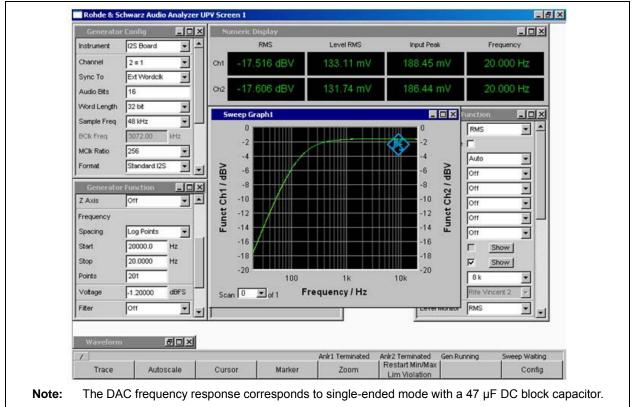


FIGURE 2-5: CODEC DAC FREQUENCY RESPONSE (CAPLESS MODE)

FIGURE 2-6: CODEC DAC FREQUENCY RESPONSE (SINGLE-ENDED MODE)



2.3 Auxiliary Port

The IS2063 SoC supports analog (line-in) signals from the external audio source. The analog (line-in) signal can be processed by the DSP to generate different sound effects (Multi-band dynamic range compression and audio widening), which can be configured by using the DSP tool.

2.4 Analog Speaker Output

The IS2063 SoC supports the following speaker output modes.

- Capless mode Recommended for headphone applications in which capless output connection helps to save the BOM cost by avoiding a large DC blocking capacitor. Figure 2-7 illustrates the analog speaker output capless mode.
- Single-ended mode Used for driving an external audio amplifier where a DC blocking capacitor is required. Figure 2-8 illustrates the analog speaker output single-ended mode.

FIGURE 2-7: ANALOG SPEAKER OUTPUT CAPLESS MODE

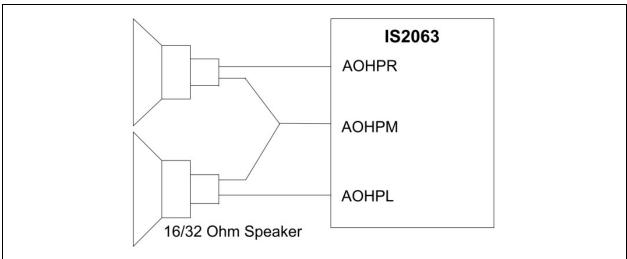
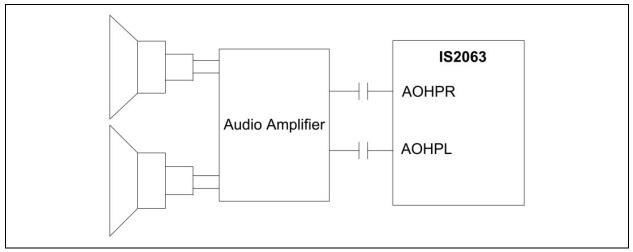


FIGURE 2-8: ANALOG SPEAKER OUTPUT SINGLE-ENDED MODE



3.0 TRANSCEIVER

The IS2063 SoC is designed and optimized for Bluetooth 2.4 GHz systems. It contains a complete radio frequency transmitter/receiver section. An internal synthesizer generates a stable clock for synchronizing with another device.

3.1 Transmitter

The internal power amplifier (PA) has a maximum output power of +4 dBm. This is applied into Class 2 or Class 3 radios without an external RF PA. The transmitter performs the IQ conversion to minimize the frequency drift.

3.2 Receiver

The low-noise amplifier (LNA) operates with TR-combined mode for the single port application. It can save the pin on the package without having an external Tx/Rx switch.

The ADC is used to sample the input analog signal and convert it into a digital signal for demodulator analysis. A channel filter is integrated into the receiver channel before the ADC to reduce the external component count and increase the anti-interference capability.

The image rejection filter is used to reject the image frequency for the low-IF architecture, and it also intended to reduce the external Band Pass Filter (BPF) component for a super heterodyne architecture.

The Received Signal Strength Indicator (RSSI) signal feedback to the processor is used to control the RF output power to make a good trade-off for effective distance and current consumption.

3.3 Synthesizer

A Synthesizer generates a clock for radio transceiver operation. The VCO inside, with a tunable internal LC tank, can reduce any variation for components. A crystal oscillator with an internal digital trimming circuit provides a stable clock for the synthesizer.

3.4 Modem

For Bluetooth 1.2 specification and below, 1 Mbps was the standard data rate based on the Gaussian Frequency Shift Keying (GFSK) modulation scheme. This basic rate modem meets Basic Data Rate (BDR) requirements of Bluetooth 2.0 with Enhanced Data Rate (EDR) specifications.

For Bluetooth 2.0 and above specifications, EDR is introduced to provide the data rates of 1/2/3 Mbps. For baseband, both BDR and EDR utilize the same 1 MHz symbol rate and 1.6 kHz slot rate. For BDR, symbol 1 represents 1-bit. However, each symbol in the payload part of the EDR packet represents 2 or 3 bits. This is achieved by using two different modulations, $\pi/4$ DQPSK and 8 DPSK.

3.5 Adaptive Frequency Hopping (AFH)

The IS2063 SoC has an AFH function to avoid RF interference. It has an algorithm to check the nearby interference and to choose a clear channel for transceiver Bluetooth signal.



NOTES:

4.0 MICROCONTROLLER

A Microcontroller is built into the SoC to execute the Bluetooth protocols. It operates from 16 MHz to higher frequencies where the firmware can dynamically adjust the trade-off between the computing power and the power consumption. In ROM version, the MCU firmware is hard-wired to minimize the power consumption for the firmware execution and to save the external Flash cost.

4.1 External Reset

The IS2063 SoC provides a watchdog timer (WDT) to reset the SoC. It has an integrated Power-on Reset (POR) circuit that resets all circuits to a known Power-on state. This action can also be driven by an external Reset signal which is used to control the device externally by forcing it into a POR state. The RST_N signal input is active-low and connection is not required in most of the applications.

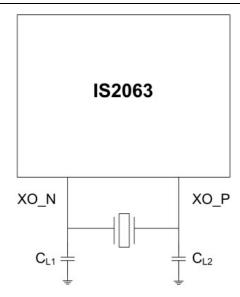
4.2 Reference Clock

The IS2063 SoC is composed of an integrated crystal oscillation function that uses a 16 MHz±10 ppm external crystal and two specified loading capacitors to provide a high quality system reference timer source. This feature is typically used to remove the initial tolerance frequency errors associated with the crystal and its equivalent loading capacitance in mass production.

The frequency trim is achieved by adjusting the crystal loading capacitance through the on-chip trim capacitors (C_{trim}). The value of trimming capacitance is 200 fF (200x10⁻¹⁵ F) per LSb at 5-bit word and the overall adjustable clock frequency is ±40 kHz (based on crystal with load capacitance, C_{I} spec = 9 pF).

Figure 4-1 illustrates the crystal connection of the IS2063 SoC with two capacitors.

FIGURE 4-1: CRYSTAL CONNECTION



Note 1: C_{trim} = 200 fF * (1 to 31); C_{int} = 3 pF.

2: $C_L = [C_{L1} \times C_{L2})/(C_{L1} + C_{L2})] + (C_{trim}/2) + C_{int}$ (set trim value as 16, then $C_{trim} = 3.2 \text{ pF}$).

3: For a 16 MHz crystal, in which C_L = 9 pF, we can get C_{L1} = C_{L2} = 9.1 pF).

4: For additional information on C_L selection, refer to the data sheet of the crystal.

NOTES:

5.0 POWER MANAGEMENT UNIT

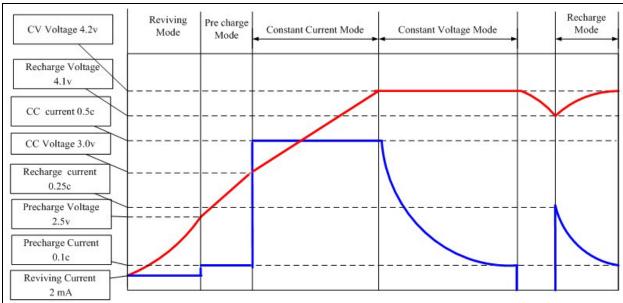
The IS2063 SoC has an integrated Power Management Unit (PMU). The main features of the PMU are a lithium-ion and lithium-polymer battery charger, and a voltage regulator. A power switch is used to switch over the power source between the battery and an adapter. Also, the PMU provides current for driving three LEDs.

5.1 Charging a Battery

The IS2063 SoC has a built-in battery charger which is optimized for lithium-ion and lithium-polymer batteries. The battery charger includes a current sensor for charging control, user programmable current regulator and high accuracy voltage regulator.

The charging current parameters are configured using the UI tool. Whenever the adapter is plugged in, the charging circuit becomes activated. Reviving, pre-charging, constant current and constant voltage modes and re-charging functions are included. The maximum charging current is 350 mA. Figure 5-1 illustrates the charging curve of a battery.

FIGURE 5-1: BATTERY CHARGING CURVE



5.2 Voltage Monitoring

The 10-bit successive approximation register ADC (SAR ADC) provides a dedicated channel for battery voltage level detection. The warning level can be programmed using the UI tool. The ADC provides a granular resolution to enable the MCU to take control over the charging process.

5.3 LDO

The built-in Low-Dropout Regulator (LDO) is used to convert the battery or adapter power for power supply. It also integrates hardware architecture to control the power-on/off procedure. The built-in programmable LDOs provide power for codec and digital I/O pads. Also, it is used to buffer the high input voltage from battery or adapter. This LDO requires 1 μF bypass capacitor.

5.4 Switching Regulator

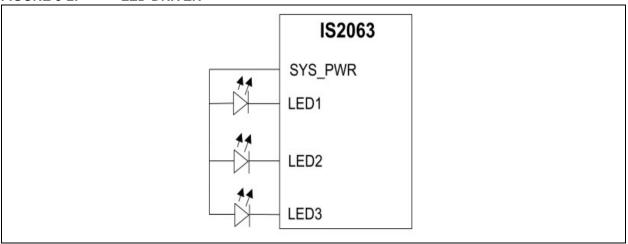
The built-in programmable output voltage regulator can convert the battery voltage to RF and baseband core power supply. This converter has a high conversion efficiency and a fast transient response.

5.5 LED Driver

The IS2063 SoC has three LED drivers to control the LEDs. The LED drivers provide enough sink current (16-step control and 0.35 mA for each step) and the LED can be connected directly to the IS2063 SoC. The LED settings can be configured using the UI tool.

Figure 5-2 illustrates the LED driver details in the IS2063 SoC.

FIGURE 5-2: LED DRIVER



5.6 Under Voltage Protection

When the voltage of the SYS_PWR pin drops below the voltage level of 2.9V, the system will shutdown automatically.

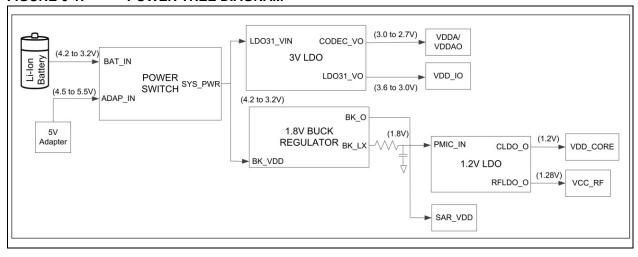
6.0 APPLICATION INFORMATION

6.1 Power Supply

Figure 6-1 illustrates the PCB connection from the BAT_IN pin to other voltage supply pins of the IS2063 SoC. The IS2063 SoC is powered through the BAT_IN input pin. If battery is not connected, an external power supply must be provided as an input to the ADAP_IN pin.

- Note 1: When an external power supply is connected to the ADAP_IN pin of the IS2063 SoC, the BAT_IN pin can be left open if battery is not connected.
 - 2: If the current to be driven is more than 120 mA, Microchip recommends to use the BAT_IN pin. If the current driven is less than 120 mA, either the ADAP_IN pin or the BAT_IN pin can be used.

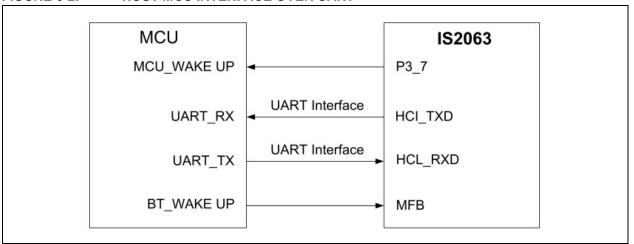
FIGURE 6-1: POWER TREE DIAGRAM



6.2 Host MCU Interface

Figure 6-2 illustrates the UART interface between the IS2063 SoC and an external MCU.

FIGURE 6-2: HOST MCU INTERFACE OVER UART



An external MCU can control the IS2063 SoC over the UART interface and wake-up the IS2063 SoC using the MFB pins. The P3_7 pin can be used to wake-up the host MCU.

Refer to the "UART_CommandSet" document for a list of functions the IS2063 SoC supports and how to use the UI tool to set up the system using the UART command.

Note:

The "UART_CommandSet" document is available for download from the Microchip web site at:www.microchip.com/IS2063.

Figure 6-3 through Figure 6-7 illustrate the timing sequences of various UART control signals.

FIGURE 6-3: POWER-ON/OFF SEQUENCE

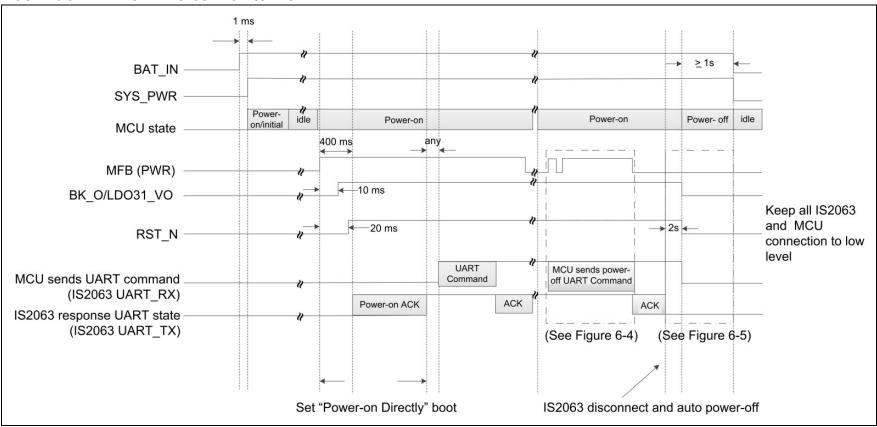


FIGURE 6-4: TIMING SEQUENCE OF RX INDICATION AFTER POWER-ON STATE

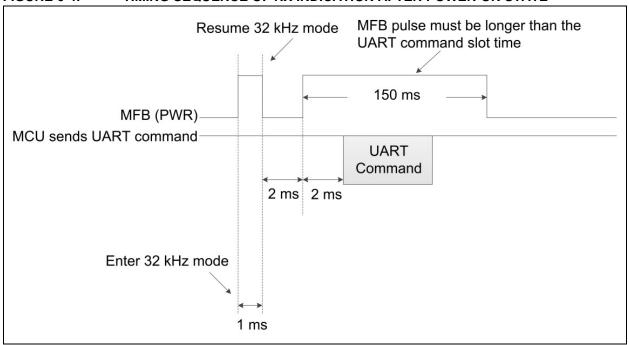
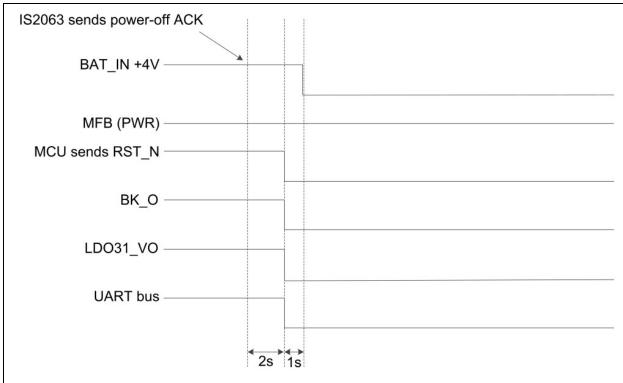


FIGURE 6-5: TIMING SEQUENCE OF POWER-OFF STATE



Note 1: EEPROM clock = 100 kHz.

- **2:** For a byte write, 0.01 ms x 32 clock x 2 = 640 μ s.
- 3: It is recommended to have a ramp-down time more than 640 µs during the power-off sequence to ensure a safe operation of the device.

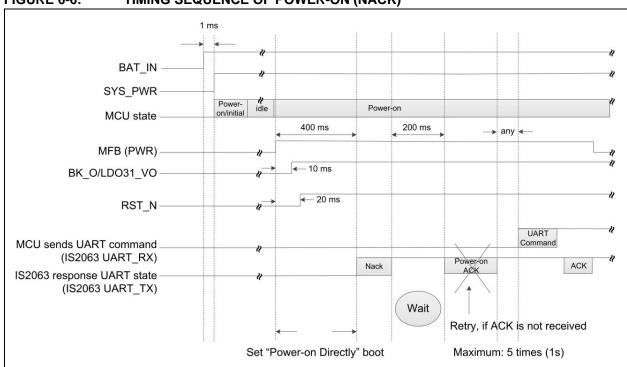
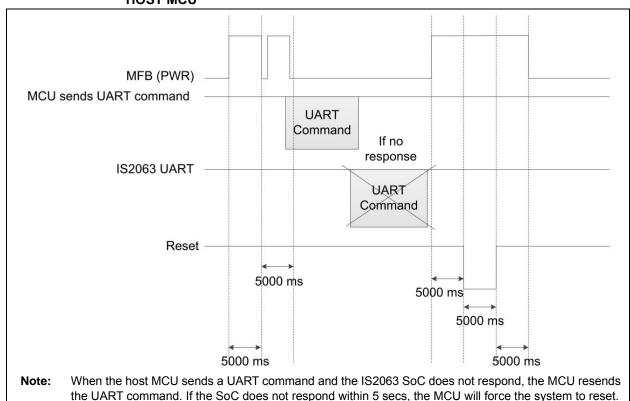


FIGURE 6-6: TIMING SEQUENCE OF POWER-ON (NACK)

FIGURE 6-7: RESET TIMING SEQUENCE IN CASE OF NO RESPONSE FROM SOC TO HOST MCU



6.3 Configuration and Programming

Configuration and firmware programming modes are entered according to the system configuration I/O pins. Table 6-1 provides the system configuration settings. The P2_0, P2_4 and EAN pins have internal pull up.

TABLE 6-1: SYSTEM CONFIGURATION SETTINGS

P2_0	P2_4	EAN	Operating Mode
High	High	Flash code: Low; ROM code: High	APP mode (Normal operation)
Low	High	Flash code: Low; ROM code: High	Test mode (Write EEPROM)
Low	Low	High	Write Flash

6.4 General Purpose I/O Pins

The IS2063 SoC provides 10 GPIOs and these GPIOs can be configured using the UI tool. Table 6-2 and Table 6-3 provide the GPIO configuration details of the IS2063 SoC.

The MFB pin must be configured as the power-on/off key and the remaining pins can be configured for any one of the default functions as provided in Table 6-2 and Table 6-3.

TABLE 6-2: IS2063 I/O PIN CONFIGURATION

I/O pin name	Default Functions
MFB	Power-on/off
P0_2	Play/Pause
P2_7	Volume up
P0_5	Volume down
P3_3	FWD
P3_1	REV

Some pins can be configured to indicate or control the external devices. The most popular applications are NFC for easy pairing and Buzzer for indication and external audio amplifier for loud speaker.

TABLE 6-3: IS2063 I/O PIN (FOR ADDITIONAL FUNCTIONS)

I/O Configurable Features	Functions	
P0_0/P1_5	Slide switch	
P0_4	NFC detect	
P0_0/P0_4	External AMP enable	

6.5 I²S Mode Application

The IS2063 SoC provides an I²S digital audio output interface to connect with the external codec or DSP. It provides 8, 16, 44.1, 48, 88.2 and 96 kHz sampling rates for 16-bit and 24-bit data formats. The I²S setting can be configured using the UI and DSP tools.

Note: The DSP and UI tools are available for download from the Microchip web site at: www.microchip.com/IS2063.

The external codec or DSP interfaces with these pins: SCLK0, RFS0, DR0 and DT0 (pin nos. 3, 2, 1, and 4 respectively).

Figure 6-8 and Figure 6-9 illustrate the I²S signal connection between the IS2063 SoC and an external DSP. Use the DSP tool to configure the IS2063 SoC as a Master/Slave.

For additional information on timing specifications, refer to **8.1** "Timing specifications".

FIGURE 6-8: IS2063 IN I²S MASTER MODE

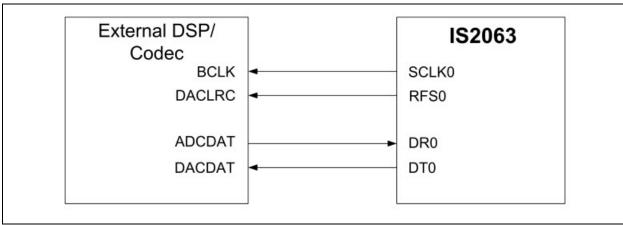
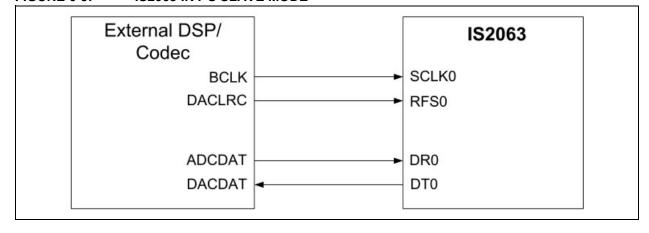


FIGURE 6-9: IS2063 IN I²S SLAVE MODE





NOTES:

7.0 ANTENNA PLACEMENT RULE

For Bluetooth-enabled products, the antenna placement affects the overall performance of the system. The antenna requires free space to radiate RF signals and it must not be surrounded by the ground plane.

Figure 7-1 illustrates a typical example of good and poor antenna placement on the main application board with the ground plane.

FIGURE 7-1: ANTENNA PLACEMENT EXAMPLES

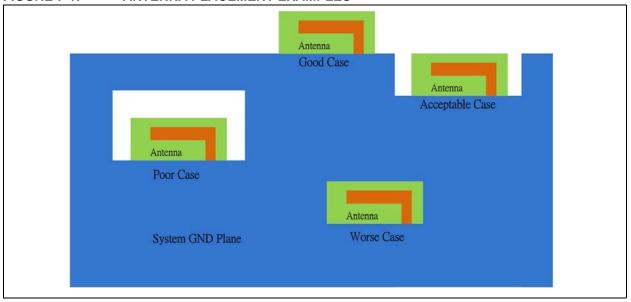
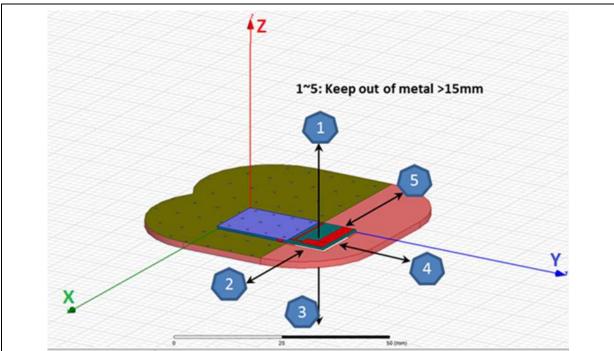


Figure 7-2 illustrates the recommended keep-out area for the PCB antenna.

FIGURE 7-2: KEEP-OUT AREA RECOMMENDED FOR PCB ANTENNA



For additional information on the antenna placement, refer to the specific antenna data sheet of the antenna

manufacturer.



NOTES:

8.0 ELECTRICAL CHARACTERISTICS

This section provides an overview of the IS2063 Stereo Audio SoC electrical characteristics. Additional information will be provided in future revisions of this document as it becomes available.

Absolute maximum ratings for the IS2063 SoC are listed below. Exposure to these maximum rating conditions for extended periods may affect device reliability. Functional operation of the device at these or any other conditions, above the parameters indicated in the operation listings of this specification, is not implied.

Absolute Maximum Ratings

Ambient temperature under bias	20°C to +70°C
Storage temperature	
Digital core supply voltage VDD_CORE	0V to +1.35\
RF supply voltage VCC_RF	0V to +1.35\
SAR ADC supply voltage SAR_VDD	0V to +2.1\
Codec supply voltage VDDA/VDDAO	0V to +3.3\
Buck supply voltage BK_VDD	0V to +4.3\
Supply voltage LDO31_VIN	0V to +4.3\
Battery input voltage BAT_IN	0V to +4.3\
Adapter input voltage ADAP_IN	0V to +7\

Note: Stresses listed under "**Absolute Maximum Ratings**" may cause permanent damage to the device. This is a stress rating only. The functional operation of the device at those or any other conditions and those indicated in the operation listings of this specification, is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 8-1 through Table 8-9 provide the recommended operating conditions and the electrical specifications of the IS2063 SoC.

TABLE 8-1: RECOMMENDED OPERATING CONDITION

Symbol	Parameter	Min.	Тур.	Max.	Unit
VDD_CORE	Digital core supply voltage	1.14	1.2	1.26	V
VCC_RF	RF supply voltage	1.22	1.28	1.34	V
SAR_VDD	SAR ADC supply voltage	1.62	1.8	1.98	V
VDDA/VDDAO	Codec supply voltage	1.8	2.8	3.0	V
VDD_IO	I/O supply voltage	3.0	3.3	3.6	V
BK_VDD	Buck supply voltage	3	3.8	4.25	V
LDO31_VIN	Supply voltage	3	3.8	4.25	V
BAT_IN	Input voltage for battery	3.2	3.8	4.25	V
ADAP_IN	Input voltage for adapter	4.5	5	5.5	V
TOPERATION	Operation temperature	-20	+25	+70	°C

Note: The PMU output powers, BK_O, CODEC_VO, RFLDO_O and CLDO_O, can be programmed through the EEPROM parameters.

TABLE 8-2: BUCK SWITCHING REGULATOR

Parameter	Min.	Тур.	Max.	Unit
Input Voltage	3.0	3.8	4.25	V
Output Voltage (Iload = 70 mA, Vin = 4V)	1.7	1.8	2.05	V
Output Voltage Accuracy	_	±5	-	%
Output Voltage Adjustable Step	_	50	-	mV/Step
Output Adjustment Range	-0.1	_	+0.25	V
Average Load Current (Iload)	120	_	-	mA
Conversion Efficiency (BAT = 3.8V, Iload = 50 mA)	_	88 ⁽¹⁾	-	%
Quiescent Current (PFM)	_	_	40	μΑ
Output Current (peak)	200	_	_	mA
Shutdown Current	_	_	<1	μΑ

Note 1: Test condition: Temperature +25°C and wired inductor 10 μH .

2: These parameters are characterized, but not tested in manufacturing.

TABLE 8-3: LOW DROP REGULATOR

Para	meter	Min.	Тур.	Max.	Unit
Input Voltage		3.0	3.8	4.25	V
Output Voltage	CODEC_VO	_	2.8	_	V
	LDO31_VO	_	3.3	_	
Output Accuracy (Vin = 3.7	V, Iload = 100 mA, +27°C)	_	±5	_	%
Output Current (average)		_	-	100	mA
Drop-out voltage (lload = maximum output cu	ırrent)	-	_	300	mV
Quiescent Current (excluding load, lload < 1 m	A)	-	45	_	μA
Shutdown Current		_	_	<1	μA

Note 1: Test condition: Temperature +25°C.

TABLE 8-4: BATTERY CHARGER

Para	meter	Min.	Тур.	Max.	Unit
Input Voltage (ADAP_IN)		4.5	5.0	5.5	V
Supply current to charger only		-	3	4.5	mA
Maximum Battery Fast Charge Current	Headroom > 0.7V (ADAP_IN = 5V)	-	350	_	mA
	Headroom = 0.3V to 0.7V (ADAP_IN = 4.5V) (Note 2)	-	175	_	mA
Trickle Charge Voltage Three	eshold	_	3	_	V
Battery Charge Termination Current, (% of Fast Charge Current)		I	10	ı	%

Note 1: Headroom = VADAP_IN - VBAT.

TABLE 8-5: LED DRIVER

Parameter	Min.	Тур.	Max.	Unit
Open-drain Voltage	-	_	3.6	V
Programmable Current Range	0	_	5.25	mA
Intensity Control	-	16	-	step
Current Step	-	0.35	-	mA
Power Down Open-drain Current	-	_	1	μA
Shutdown Current	-	-	1	μA

Note 1: Test condition: BK_O = 1.8V, temperature +25°C.

^{2:} These parameters are characterized, but not tested in manufacturing.

^{2:} When VADAP_IN - VBAT > 2V, the maximum fast charge current is 175 mA for thermal protection.

^{3:} These parameters are characterized, but not tested in manufacturing.

^{2:} These parameters are characterized, but not tested in manufacturing.

TABLE 8-6: AUDIO CODEC DIGITAL TO ANALOG CONVERTER

T = +25°C, V _{DD} = 2.8V, 1 kHz sine wave input, Bandwidth = 20 Hz to 20 kHz					
Parameter (Condition)		Min.	Тур.	Max.	Unit
Output Sampling Rate		_	128	_	f _s
Resolution		16	_	20	Bit
Output Sample Rate		8	_	48	kHz
Signal to Noise Ratio (Note 1) (SNR @capless mode) for 48 kHz		ı	96	_	dB
Signal to Noise Ratio (Note 1) (SNR @single-ended mode) for 48 kHz	, ,		98	_	dB
Digital Gain	Digital Gain		_	4.85	dB
Digital Gain Resolution		_	2 to 6	_	dB
Analog Gain		-28	-	3	dB
Analog Gain Resolution		-	1	_	dB
Output Voltage Full-scale Swing (AVDD = 2.8V)		495	742.5	_	mV/rms
Maximum Output Power (16 Ohm load)		-	34.5	_	mW
Maximum Output Power (32 Ohm load)		ı	17.2	_	mW
Allowed Load	Resistive	_	16	O.C.	Ohm
	Capacitive		_	500	pF
THD+N (16 Ohm load) (Note 2)		-	0.05	_	%
Signal to Noise Ratio (SNR @ 16 Ohm load) (Note 3)			98	_	dB

Note 1: fin = 1 kHz, B/W = 20 Hz to 20 kHz, A-weighted, THD+N < 0.01%, 0 dBFS signal, Load = 100 kOhm.

- 2: fin = 1 kHz, B/W = 20 Hz to 20 kHz, A-weighted, -1 dBFS signal, Load = 16 Ohm.
- 3: fin = 1 kHz, B/W = 20 Hz to 20 kHz, A-weighted, THD+N < 0.05%, 0 dBFS signal, Load = 16 Ohm.
- 4: These parameters are characterized, but not tested in manufacturing.

TABLE 8-7: AUDIO CODEC ANALOG TO DIGITAL CONVERTER

T = +25°C, V _{DD} = 2.8V, 1 kHz sine wave input, Bandwidth = 20 Hz to 20 kHz					
Parameter (Condition)	Min.	Тур.	Max.	Unit	
Resolution	-	-	16	Bit	
Output Sample Rate	8	_	48	kHz	
Signal to Noise Ratio (Note 1) (SNR @MIC or Line-in mode)	_	92	-	dB	
Digital Gain	-54	_	4.85	dB	
Digital Gain Resolution	-	2 to 6	-	dB	
MIC Boost Gain	-	20	-	dB	
Analog Gain	-	_	60	dB	
Analog Gain Resolution	-	2.0	-	dB	
Input full-scale at maximum gain (differential)	-	4	-	mV/rms	
Input full-scale at minimum gain (differential)	-	800	-	mV/rms	
3 dB bandwidth	-	20	-	kHz	
Microphone mode (input impedance)	_	24	-	kOhm	
THD+N (microphone input) at 30 mVrms input	_	0.02	_	%	

Note 1: fin = 1 kHz, B/W = 20 Hz to 20 kHz, A-weighted, THD+N < 1%, 150 mV_{PP} input.

2: These parameters are characterized, but not tested in manufacturing.

TABLE 8-8: TRANSMITTER SECTION FOR BDR AND EDR

Parameter	Min.	Тур.	Max.	Bluetooth specification	Unit
RF Transmit power	_	2 ⁽³⁾	_	-6 to 4	dBm
EDR/BDR relative transmit power	-4	-1.8	1	-4 to 1	dB

- Note 1: The RF TX power is modulation value.
 - **2:** The RF Transmit power is calibrated during production using the MP tool software and MT8852 Bluetooth test equipment.
 - **3:** Test condition: VCC_RF = 1.28V, temperature +25°C.

TABLE 8-9: RECEIVER SECTION FOR BDR AND EDR

	Modulation	Min.	Тур.	Max.	Bluetooth specification	Unit
Sensitivity at 0.1% BER	GFSK	_	-89	_	≤-70	dBm
Sensitivity at 0.01% BER	π/4 DQPSK	_	-90	-	≤-70	dBm
	8 DPSK	_	-83	_	≤-70	dBm

Note 1: Test condition: VCC_RF = 1.28V, temperature +25°C.

2: These parameters are characterized, but not tested in manufacturing.

8.1 Timing specifications

Figure 8-1 and Figure 8-2 illustrate the timing diagram of the IS2063 SoC in $\rm I^2S$ and PCM modes.

FIGURE 8-1: TIMING DIAGRAM FOR I²S MODES (MASTER/SLAVE)

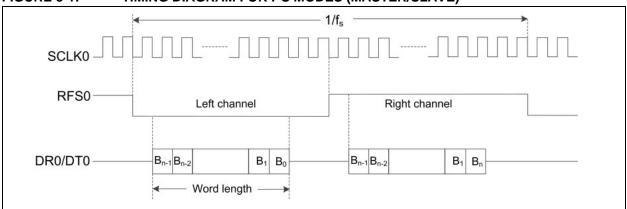


FIGURE 8-2: TIMING DIAGRAM FOR PCM MODES (MASTER/SLAVE)

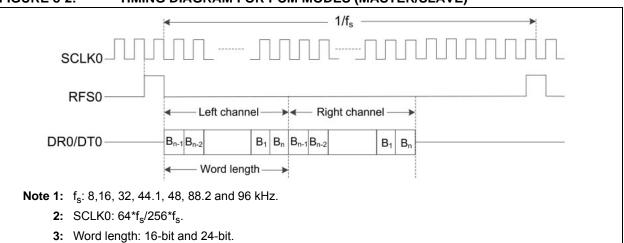


Figure 8-3 illustrates the audio interface timing diagrams.

FIGURE 8-3: AUDIO INTERFACE TIMING DIAGRAM

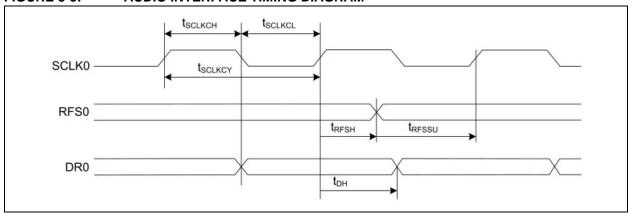


Table 8-10 provides the timing specifications of audio interface.

TABLE 8-10: AUDIO INTERFACE TIMING SPECIFICATIONS

Parameter	Symbol	Min.	Тур.	Max.	Unit
SCLK0 duty ratio	d _{SCLK}	-	50	_	%
SCLK0 cycle time	t _{SCLKCY}	50	_	_	ns
SCLK0 pulse width high	t _{SCLKCH}	20	_	_	ns
SCLK0 pulse width low	t _{SCLKCL}	20	-	_	ns
RFS0 setup time to SCLK0 rising edge	t _{RFSSU}	10	_	_	ns
RFS0 hold time from SCLK0 rising edge	t _{RFSH}	10	_	_	ns
DR0 hold time from SCLK0 rising edge	t _{DH}	10	_	_	ns

Note: Test Conditions: Slave Mode, $f_s = 48 \text{ kHz}$, 24-bit data and SCLK0 period = 256 f_s .

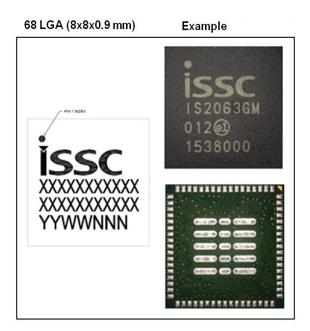


9.0 PACKAGE INFORMATION

9.1 Package Marking Information

Figure 9-1 illustrates the package marking information of the IS2063 SoC.

FIGURE 9-1: PACKAGE MARKING INFORMATION



Legend:

XXX: Chip serial number version and

Pb-free JEDEC designator for SAC305(*1)

YY: Year code (last 2 digits of calendar year)
WW: Week code (week of January 1 is week "01")

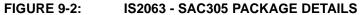
NNN: Alphanumeric traceability code

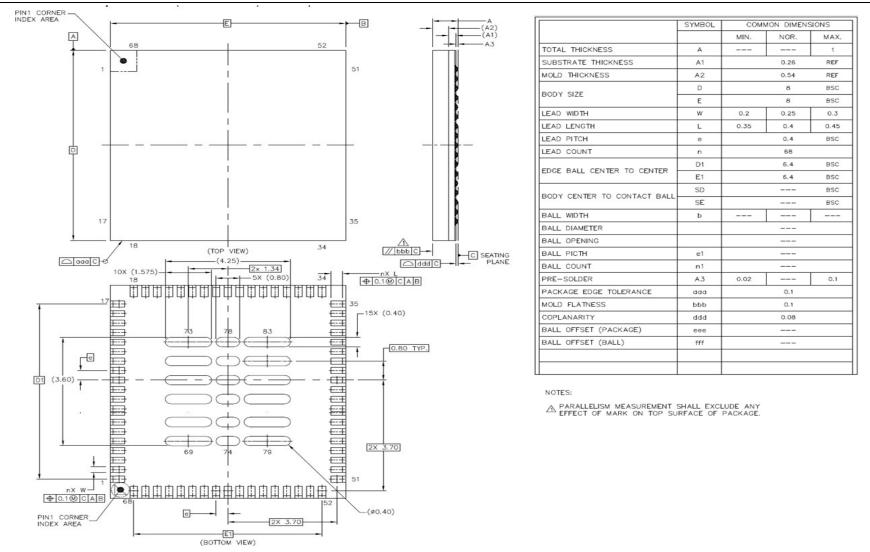
Note

(1) SAC305 is the pre-solder version. Customer need to take care solder paste before screen printing.

9.2 Package Details

Figure 9-2 illustrates the package details of the IS2063 SoC.

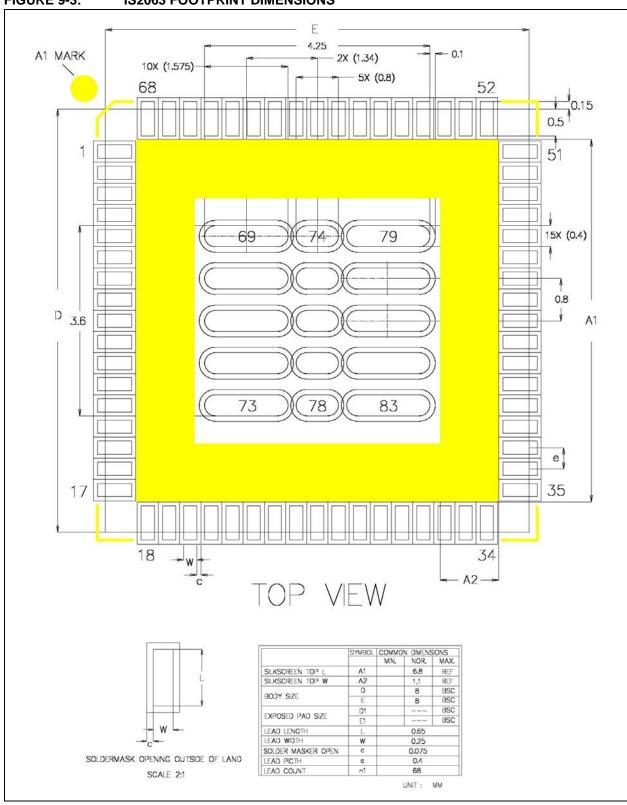




9.3 Footprint Dimensions

Figure 9-3 illustrates the footprint dimensions of the IS2063 SoC.

FIGURE 9-3: IS2063 FOOTPRINT DIMENSIONS





10.0 REFLOW PROFILE AND STORAGE CONDITION

Figure 10-1 and Figure 10-2 illustrate the reflow profiles and stencil information of the IS2063 SoC.

10.1 Stencil of SMT Assembly Suggestion

10.1.1 STENCIL TYPE AND THICKNESS

- · Laser cutting
- · Stainless steel
- Thickness: 0.5 mm pitch, thickness more than 0.15 mm

10.1.2 APERTURE SIZE AND SHAPE FOR TERMINAL PAD

- · Aspect ratio (width/thickness) is more than 1.5
- Aperture shape
 - The stencil aperture is designed to match the pad size on the PCB
 - Oval-shape opening is used to get the optimum paste release
 - Rounded corners to minimize the clogging
 - Positive taper walls (5° tapering) with the bottom opening larger than the top opening

10.1.3 APERTURE DESIGN FOR THERMAL PAD

- Small multiple openings are used instead of one big opening, refer Figure 10-1
- 60 to 80% solder paste coverage
- · Rounded corners to minimize clogging
- Positive taper walls (5° tapering) with the bottom opening larger than the top opening, see Figure 10-2



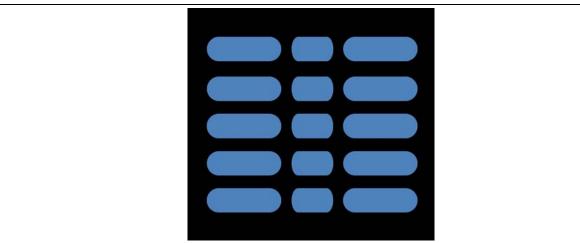
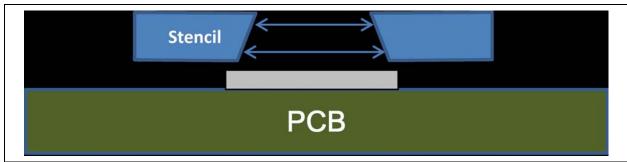


FIGURE 10-2: STENCIL TYPE



IS2063

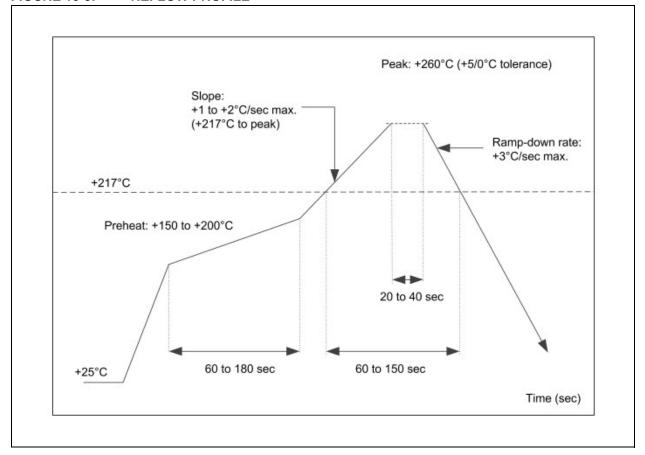
10.2 Reflow Condition

Figure 10-3 illustrates the reflow profile and the following are its specific features:

- Standard condition: IPC/JEDEC J-STD-020
- Preheat: +150 °C to +200 °C for 60 to 180 seconds
- Average ramp-up rate (+217 °C to peak):
 +1 °C /sec to +2 °C /sec max

- Temperature maintained above +217 °C : 60 to 150 seconds
- Time within +5 °C of actual peak temperature: 20 to 40 seconds
- Peak temperature: +260 °C (+5/-0 °C tolerance)
- Ramp-down rate (peak to +217°C): +3°C/sec. max
- Time +25 °C to peak temperature: 8 minutes max
- · Cycle interval: 5 minutes

FIGURE 10-3: REFLOW PROFILE



10.3 Storage Condition

Users must follow these specific storage conditions for the IS2063 SoC. $\label{eq:condition} % \begin{center} \end{center} % \begin{center} \end{center}$

- Calculated shelf life in the sealed bag: 24 months at <40 °C and <90% relative humidity (RH)
- Once the bag is opened, devices that are subjected to reflow solder or other high temperature process must be mounted within 168 hours of factory conditions, that is <30 °C /60% RH

Figure 10-4 illustrates the IS2063 SoC bag labeling details.

FIGURE 10-4: IS2063 SOC STORAGE CONDITIONS

	Caution This bag contains MOISTURE-SENSITIVE DEVICES	LEVEL 3 If blank, see adjacent bar code label
	d shelf life in sealed bag : 24 months a ative humidity(RH)	t < 40°C and
2. Peak pack	kage body temperature: If blank, see adjacent	°C I bar code label
	is opened, devices that will be subject other high temperature process must	
	ed within: 168 hours of factor of blank, see adjacent bar code label /60% RH, or	ry conditions
b) Stored	per J-STD-033	
4. Devices re	equire bake, before mounting, if:	
,	ity Indicator Card reads >10% for leves or > 60% for level 2 devices when	^
b) 3a or 3	Bb are not met.	
If baking is bake proc	s required, refer to IPC/JEDEC J-STE edure.	0-033 for
Bag Seal Da	ate:	el
Note: Level	and body temperature defined by IPC/JEDI	EC J-STD-020



11.0 ORDERING INFORMATION

Table 11-1 provides the ordering information of the IS2063 SoC.

TABLE 11-1: ORDERING INFORMATION

Device	Bluetooth Version	Package	Part Number
IS2063	Bluetooth 4.2, BDR/EDR/BLE SoC with integrated 1 microphone and stereo speaker output, and I ² S digital interface	8x8x0.9 mm, 68-LGA package	IS2063GM-0P2

Note: The IS2063 SoC can be purchased through a Microchip representative. Go to http://www.microchip.com/ for the ordering information.



APPENDIX A: REFERENCE CIRCUIT

Figure A-1 through Figure A-4 illustrate the IS2063 reference schematics for the stereo headset applications.

FIGURE A-1: IS2063 REFERENCE CIRCUIT FOR STEREO HEADSET APPLICATIONS

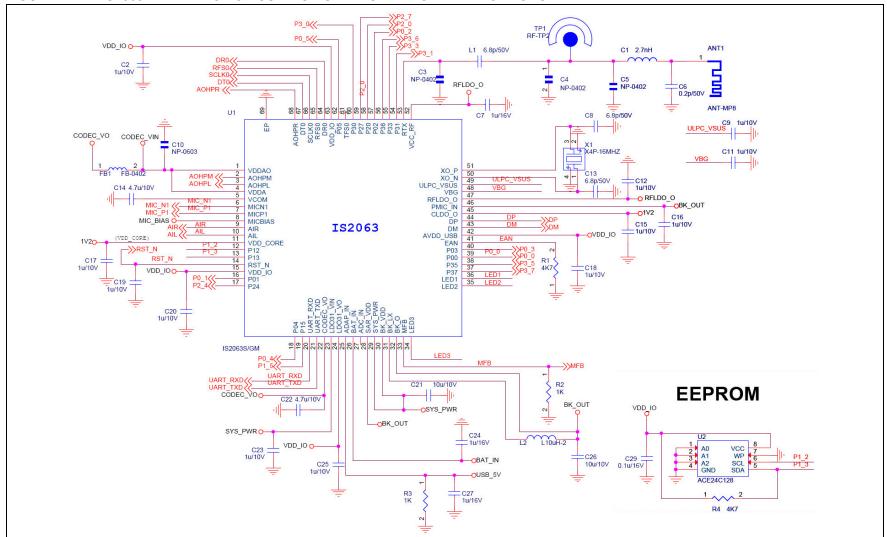


FIGURE A-2: IS2063 REFERENCE CIRCUIT FOR STEREO HEADSET APPLICATIONS

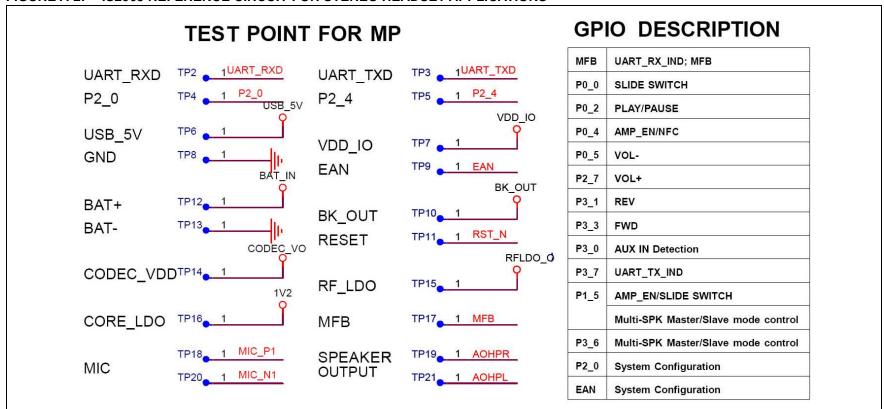


FIGURE A-3:

IS2063 REFERENCE CIRCUIT FOR STEREO HEADSET APPLICATIONS

FIGURE A-4:

STEREO AUX LINE INPUT STEREO SPEAKER OUTPUT MIC INPUT D1 SPE0572 *P30 Low Active SPK JACK OMIC_BIAS Line In Detect P3 PJ-2001-5K 0.1u/16V MIC_P1 C38 P2 PJ-3894D-S125 R13 D4 SPE0572 470p/50V SPE0572 **PUSH BUTTON USB CONNECTOR** MFB/Power MFB<< MFB 0.015u/16V PT-6038N PT-6038N Pf USBM3121-051-1-BN-R SYS_PWR L3 FB-0603 PLAY/PAUSE VOL-REV P0_2((P0_2 FB-0603 D10 D11 SPE0572 SPE0572 SPE0572 BATTERY CONNECTOR RESET IC (OPTION) RST_N RESET All ESD diodes in this schematics are reserved for testing and can be removed if ESD can be pass G691L293 without adding it. MMBT3904 All ESD diodes in this schematics are reserved for the testing. Note:

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APPENDIX B: REVISION HISTORY

Revision A (June 2016)

This is the initial released version of this document.

Revision B (January 2017)

This revision includes the following changes as well as minor updates to text and formatting which were incorporated throughout the document.

TABLE B-1: MAJOR SECTION UPDATES

Section	Update Description
1.0 Device Overview	Added "USB" details and updated "voice prompt" details in Table 1-1. Updated the pin description in Table 1-2. Updated Figure 1-1
2.0 Audio	Updated Figure 2-1.
4.0 Microcontroller	Deleted section "4.1 Memory"
9.0 Package Information	Updated Figure 9-1 and Figure 9-2 deleted Figure 9-3.
11.0 Ordering Information	Updated the P/N from IS2063GM to IS2063GM-0P2 in Table 11-1.
Appendix A: Reference Circuit	Updated Figure A-1 through Figure A-4.



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ISBN: 978-1-5224-1286-1



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